

5 V, 1 A H-Bridge Motor Driver

DESCRIPTION

The SIP2100 is an integrated, buffered H-bridge with TTL and CMOS compatible inputs with the capability of delivering up to 1 A continuous current at 5 V V_{DD} supply.

The SIP2100 has two independent logic inputs that can set four different motor operation modes: normal rotation, reverse rotation, stop (idling) and braking. The internal shoot-through protection logic also prevents upper and lower outputs from being turned on simultaneously.

The SiP2100 offers high efficiency with an extremely low operating current. The device also benefits from over temperature protection with a shut down hysteresis of 20 °C. The SIP2100 is available in SOIC8 package.

FEATURES

- · 1 A drive capability
- Optimized for 5 V V_{DD} bias
- Extremely low idle current
- Shoot-through protection scheme
- · Thermal shutdown

 Material categorization: For definitions of compliance please see www.vishay.com/doc?99912



ROHS COMPLIANT HALOGEN FREE

APPLICATIONS

- · High performance servo
- Optical/tape disk drives
- · Brush/stepper motor driver

PACKAGE OUTLINE

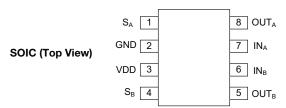


Fig. 1 - Package and Pinout

FUNCTIONAL BLOCK DIAGRAM AND TRUTH TABLE

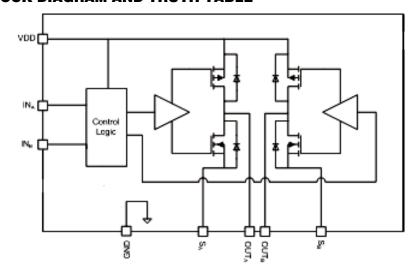


Fig. 2 - Functional Block Diagram

| TRUTH TABLE | | | | | |
|-----------------|-----------------|------------------|------------------|--|--|
| IN _A | IN _B | OUT _A | Out _B | | |
| 1 | 0 | 1 | 0 | | |
| 0 | 1 | 0 | 1 | | |
| 0 | 0 | 0 | 0 | | |
| 1 | 1 | HiZ | HiZ | | |

Document Number: 63949 S12-2801-Rev. B, 10-Dec-12 For technical questions, contact: powerictechsupport@vishay.com

SiP2100

Vishay Siliconix



| ABSOLUTE MAXIMUM RATINGS (T _A = 25 °C, unless otherwise noted) | | | | | |
|---|------------------|--------------------------|------|--|--|
| Electrical Parameter | Conditions | Limits | Unit | | |
| V_{DD} | Reference to GND | - 0.3 to 6 | | | |
| OUT _A , OUT _B | Reference to GND | - 0.3 to 6 | V | | |
| S _A , S _B | Reference to GND | - 0.3 to 1 | v | | |
| IN _A , IN _B | Reference to GND | - 0.3 to V _{DD} | | | |
| Temperature | | | | | |
| Operating Temperature | | - 40 to 85 | °C | | |
| Max. Operating Junction Temperature | | 150 | | | |

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating/conditions for extended periods may affect device reliability.

| RECOMMENDED OPERATING CONDITIONS | | | | | |
|----------------------------------|------|------|------|------|--|
| Parameter | Min. | Тур. | Max. | Unit | |
| V _{DD} | 3.8 | 5 | 5.5 | V | |
| Temperature | | | | | |
| Operating Junction Temperature | 0 | | 125 | °C | |
| Recommended Ambient Temperature | 0 | | 70 | | |

| THERMAL RESISTANCE RATINGS | | | | | |
|--|---------------------------------------|-------------|-------|--|--|
| Parameter | | Max. | Unit | | |
| Thermal Besistance (Junation to Ambient) | SO-8, R _{thJA} | 153 | °C/W | | |
| Thermal Resistance (Junction to Ambient) | SO-8 PowerPAD, R _{thJC} | 40 | *C/VV | | |
| Power Dissipation | SO-8, T _A = 70 °C | 522 | mW | | |
| Fower Dissipation | SO-8 PowerPAD, T _A = 70 °C | 2 | W | | |
| Junction Temperature | | - 65 to 150 | °C | | |
| Storage Temperature | | - 55 to 150 | | | |





| SPECIFICATIONS ($T_A = 25$ °C, unless otherwise specified) | | | | | | | |
|--|----------------------|------------------------------|--------------------------|-------|--------|-------------------|---------------------------------------|
| Parameter | Symbol | | Test Conditions | | Limits | | |
| Parameter | Symbol | V _{DD} = 5 V | | Min.a | Typ.b | Max. ^a | Unit |
| Driver Power Supply | | | | | | | |
| | | IN = 10 | 00 kHz | | 250 | 300 | |
| V _{DD} Bias Supply Current | I _{DD} | IN = 2 | 0 kHz | | 150 | 180 | μΑ |
| | | Quiesce | ent state | | 50 | | |
| V _{DD} Rising Threshold | V _{DD TH_R} | V _{DD} | rising | | 2.8 | 3 | V |
| V _{DD} Falling Threshold | V _{DD TH_F} | V _{DD} f | alling | 2 | 2.5 | | , v |
| V _{DD} UVLO Hysteresis | V _{DD UVLO} | | | | 300 | | mV |
| Input Logic | | | | | | | |
| Input Voltage High | VIN _H | | | 2 | | | ٧ |
| Input Voltage Low | VINL | | | | | 0.7 | \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ |
| Input Sourcing Current | I _{INH} | | | | | 1 | μΑ |
| Input Sinking Current | I _{INL} | | | - 1 | | | |
| Output Stage | | | | | | | |
| Output Voltage High | V | I _{OUT} = - 500 mA | | 4.4 | | | |
| Output voltage Flight | V _{OUTH} | I _{OUT} = - 1000 mA | V _{DD} = 4.75 V | 4.25 | | | ٧ |
| Output Voltage Low | V | I _{OUT} = + 500 mA | v _{DD} = 4.75 v | | | 0.25 |] |
| Output voltage Low | V _{OUTL} | I _{OUT} = + 1000 mA | | | | 0.5 | |
| Output High Propagation Delay | TP _{LH} | | | | 20 | 25 | nS |
| Output Low Propagation Delay | TP _{HL} | | | | 20 | 25 | 115 |
| Thermal Protection | | | | | | | |
| Thermal Shutdown Threshold | | | | | 150 | | - °C |
| Thermal Shutdown Hysteresis | | | | | 20 | | |

Notes:

a. Pulse test; pulse width $\leq 300~\mu s,$ duty cycle $\leq 2~\%.$

b. Guaranteed by design, not subject to production testing.

| PIN DESCRIPTION (SOIC PACKAGE) | | | | |
|--------------------------------|------------------|--|--|--|
| Pin Number | Name | Function | | |
| 1 | S _A | Driver output return A | | |
| 2 | GND | Analog ground of internal logic | | |
| 3 | V _{DD} | Input of internal logic bias and power stage | | |
| 4 | S _B | Driver output return B | | |
| 5 | OUT _B | Driver output B | | |
| 6 | IN _B | Driver input B | | |
| 7 | IN _A | Driver input A | | |
| 8 | OUT _A | Driver output A | | |

TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)

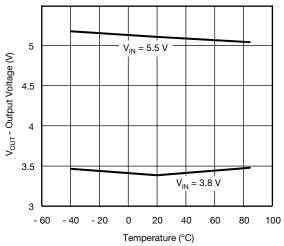


Fig 1. Output Voltage vs. Temperature (at 1.5 A Load)

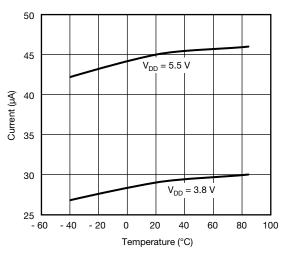


Fig 3. Quiescent Current vs. Temperature

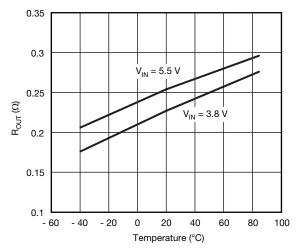


Fig 5. R_{OUT} vs. Temperature

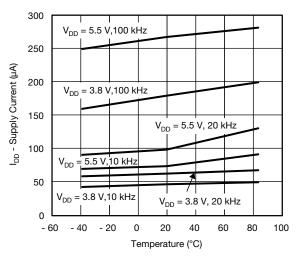


Fig 2. Supply Current I_{DD} vs. Temperature

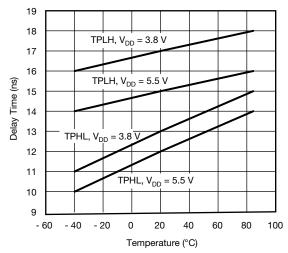


Fig 4. Propagation Delay vs. Temperature

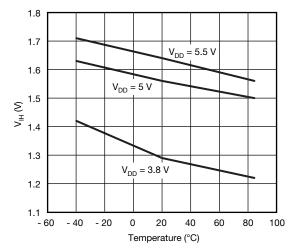


Fig 6. PWM Rising Threshold vs. Temperature



TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)

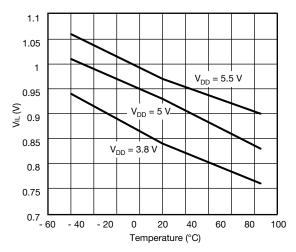


Fig 7. PWM Falling Threshold vs. Temperature

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SOIC (NARROW): 8-LEAD JEDEC Part Number: MS-012







| | MILLIM | MILLIMETERS INCHES | | HES | |
|------------------------------|----------|--------------------|-----------|-------|--|
| DIM | Min | Max | Min | Max | |
| Α | 1.35 | 1.75 | 0.053 | 0.069 | |
| A ₁ | 0.10 | 0.20 | 0.004 | 0.008 | |
| В | 0.35 | 0.51 | 0.014 | 0.020 | |
| С | 0.19 | 0.25 | 0.0075 | 0.010 | |
| D | 4.80 | 5.00 | 0.189 | 0.196 | |
| Е | 3.80 | 4.00 | 0.150 | 0.157 | |
| е | 1.27 BSC | | 0.050 BSC | | |
| Н | 5.80 | 6.20 | 0.228 | 0.244 | |
| h | 0.25 | 0.50 | 0.010 | 0.020 | |
| L | 0.50 | 0.93 | 0.020 | 0.037 | |
| q | 0° | 8° | 0° | 8° | |
| S | 0.44 | 0.64 | 0.018 | 0.026 | |
| FCN: C-06527-Rev 11-Sen-06 | | | | | |

DWG: 5498

Document Number: 71192 www.vishay.com 11-Sep-06



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Revision: 02-Oct-12 Document Number: 91000